



SINGLE 2 INPUT POSITIVE NAND GATE

Description

The 74LVC1G00 is a single 2-input positive NAND gate with a standard totem pole output. The device is designed for operation with a power supply range of 1.65V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

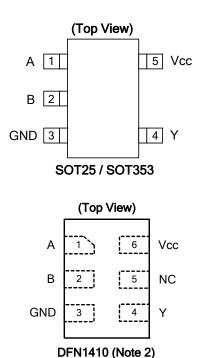
The gate performs the positive Boolean function:

 $Y = \overline{A \bullet B}$ or $Y = \overline{A} + \overline{B}$

Features

- Wide Supply Voltage Range from 1.65 to 5.5V
- ± 24mA Output Drive at 3.3V
- CMOS low power consumption
- IOFF Supports Partial-Power-Down Mode Operation
- Inputs accept up to 5.5V
- ESD Protection Tested per JESD 22
 Exceeds 200-V Machine Model (A115-A)
 Exceeds 2000-V Human Body Model (A114-A)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- Range of Package Options
- Direct Interface with TTL Levels
- SOT25, SOT353, and DFN1410: Assembled with "Green" Molding Compound (no Br, Sb)
- Lead Free Finish/ RoHS Compliant (Note 1)

Pin Assignments



Applications

- Voltage Level Shifting
- General Purpose Logic
- Power Down Signal Isolation
- Wide array of products such as.
 - PCs, networking, notebooks, netbooks, PDAs
 - o Computer peripherals, hard drives, CD/DVD ROM
 - o TV, DVD, DVR, set top box
 - o Cell Phones, Personal Navigation / GPS
 - o MP3 players ,Cameras, Video Recorders

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead_free.html.

2. Pin 2 and pin 5 of the DFN1410 package are internally connected.

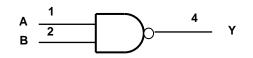


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Pin Descriptions

Pin Name	Description	
А	Data Input	
В	Data Input	
GND	Ground	
Y	Data Output	
Vcc	Supply Voltage	
NC	No Connection	

Logic Diagram



Function Table

Inp	Inputs		
Α	В	Y	
Н	Н	L	
L	Х	Н	
Х	L	Н	



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Absolute Maximum Ratings (Note 3)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high impedance or I _{OFF} state	-0.5 to 6.5	V
Vo	Voltage applied to output in high or low state	-0.3 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current V _I <0	-50	mA
Ι _{ΟΚ}	Output Clamp Current	-50	mA
Ι _Ο	Continuous output current	±50	mA
	Continuous current through Vdd or GND	±100	mA
TJ	Operating Junction Temperature	-40 to 150	°C
T _{STG}	Storage Temperature	-65 to 150	°C

Notes: 3. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

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Recommended Operating Conditions (Note 4)

Symbol		Parameter	Min	Max	Unit
N		Operating	1.65	5.5	V
V _{CC}	Operating Voltage	Data retention only	1.5		V
		V _{CC} = 1.65V to 1.95V	$0.65 \times V_{CC}$		
N/	High lovel loput Veltage	V _{CC} = 2.3V to 2.7V	1.7		V
VIH	High-level Input Voltage	$V_{CC} = 3V$ to 3.6V	2		v
		$V_{CC} = 4.5V$ to 5.5V	0.7 X V _{CC}		
		V _{CC} = 1.65V to 1.95V		0.35 X V _{CC}	
		V _{CC} = 2.3V to 2.7V		0.7	V
VIL	Low-level input voltage	V _{CC} = 3V to 3.6V		0.8	V
		V _{CC} = 4.5V to 5.5V		0.3 X V _{CC}	
VI	Input Voltage		0	5.5	V
Vo	Output Voltage		0	V _{CC}	V
		V _{CC} = 1.65V		-4	
		V _{CC} = 2.3V		-8	
I _{OH}	High-level output current)/		-16	mA
		$V_{CC} = 3V$		-24	
		$V_{CC} = 4.5V$		-32	
		V _{CC} = 1.65V		4	
		$V_{CC} = 2.3 V$		8	
I _{OL}	Low-level output current	$V_{CC} = 3V$		16	mA
				24	
		$V_{CC} = 4.5V$		32	
	Innut transition rise or fall	$V_{CC} = 1.8V \pm 0.15V, 2.5V \pm 0.2V$		20	
Δt/ΔV	Input transition rise or fall rate	$V_{CC} = 3.3V \pm 0.3V$		10	ns/V
		$V_{\rm CC} = 5V \pm 0.5V$		5	
T _A	Operating free-air temperature		-40	85	٥C

Notes: 4. Unused inputs should be held at Vcc or Ground.



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Electrical Characteristics (All typical values are at Vcc = 3.3V, T_A = 25°C)

Symbol	Parameter	Test Conditions	Vcc	Min	Тур.	Max	Unit
		I _{OH} = -100μA	1.65 V to 5.5V	V _{CC} – 0.1			
	High Level Output	I _{OH} = -4mA	1.65 V	1.2			
		I _{OH} = -8mA	2.3V	1.9			v
V _{OH}	Voltage	I _{OH} = -16mA	2.14	2.4			V
		I _{OH} = -24mA	-3 V	2.3			
		I _{OH} = -32mA	4.5 V	3.8			
		I _{OL} = 100μΑ	1.65 V to 5.5V			0.1	
		I _{OL} = 4mA	1.65 V			0.45	
.,		I _{OL} = 8mA	2.3 V			0.3	
V _{OL}	High-level Input Voltage	I _{OL} = 16mA	2.14			0.4	V
		I _{OL} = 24mA	-3 V			0.55	
		I _{OL} = 32mA	4.5 V			0.55	
lı	Input Current	$V_{I} = 5.5 V \text{ or GND}$	0 to 5.5 V			± 5	μA
I _{OFF}	Power Down Leakage Current	$V_{I} \text{ or } V_{O} = 5.5 V$	0			± 10	μΑ
I _{CC}	Supply Current	$V_1 = 5.5V \text{ of GND}$ $I_0=0$	1.65 V to 5.5V			10	μA
ΔI _{CC}	Additional Supply Current	One input at V_{CC} – 0.6 V Other inputs at V_{CC} or GND	3 V to 5.5V			500	μA
Ci	Input Capacitance	$V_i = V_{CC} - or GND$	3.3		3.5		pF
	The second Descriptions	SOT25	(Note 5)		204		°C/W
θ _{JA}	Thermal Resistance Junction-to-Ambient	SOT353	(Note 5)		371		°C/W
		DFN1410	(Note 5)		430		°C/W
	Thermal Resistance	SOT25	(Note 5)		52		°C/W
θ _{JC}	Junction-to-Case	SOT353	(Note 5)		143		°C/W
		DFN1410	(Note 5)		190		°C/W

Over recommended free-air temperature range (unless otherwise noted)

Notes: 5. Test condition for SOT25, SOT353, and DFN1410: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.



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Switching Characteristics

Parameter	From			Vcc = 1.8 V ± 0.15V		2.5 V .2V	Vcc = ± 0			= 5 V 0.5V	Unit
	(Input)	(OUTPUT)	Min	Max	Min	Max	Min	Max	Min	Max	
t _{pd}	A or B	Y	2.2	7.2	0.9	4.4	0.8	3.8	0.8	3.4	ns

Over recommended free-air temperature range, CL = 15pF (see Figure 1)

Over recommended free-air temperature range, CL = 30 or 50pF as noted (see Figure 2)

Parameter	From	-		Vcc = 1.8 V ± 0.15V		2.5 V .2V	Vcc = ± 0			= 5 V 0.5V	Unit
	(Input)	(OUTPUT)	Min	Max	Min	Max	Min	Max	Min	Max	
t _{pd}	A or B	Y	3.1	9.0	1.3	5.5	1.0	4.7	1.0	4.0	ns

Operating Characteristics

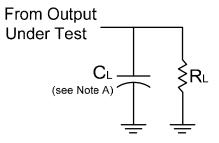
T_A = 25 °C

	Parameter	Test Conditions	Vcc = 1.8 V TYP	Vcc = 2.5 V TYP	Vcc = 3.3 V TYP	Vcc = 5 V TYP	Unit
C _{pd}	Power dissipation capacitance	f = 10 MHz	22	22	23	25	pF



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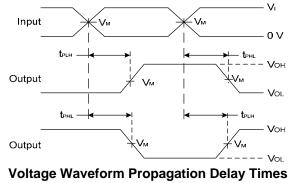
Parameter Measurement Information



Vcc	Inj	puts	V _M	CL	RL
100	VI	t _r /t _f	¥ N	5L	ΝL
1.8V±0.15V	V _{CC}	≤2ns	V _{CC} /2	15pF	1MΩ
2.5V±0.2V	V _{CC}	≤2ns	V _{CC} /2	15pF	1MΩ
3.3V±0.3V	3V	≤2.5ns	1.5V	15pF	1MΩ
5V±0.5V	V _{CC}	≤2.5ns	V _{CC} /2	15pF	1MΩ



Voltage Waveform Pulse Duration



Inverting and Non Inverting Outputs

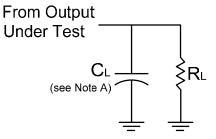
Figure 1. Load Circuit and Voltage Waveforms

- Notes: A. Includes test lead and test apparatus capacitance.
 - B. All pulses are supplied at pulse repetition rate \leq 10 MHz.
 - C. Inputs are measured separately one transition per measurement.
 - D. t_{PLH} and t_{PHL} are the same as $t_{\text{PD.}}$



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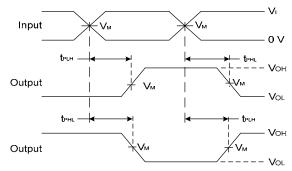
Parameter Measurement Information (Continued)



Vcc	Inputs		V _M	CL	RL
100	VI	t _r /t _f	¥ IVI		IVL
1.8V±0.15V	Vcc	≤2ns	V _{CC} /2	30pF	1KΩ
2.5V±0.2V	Vcc	≤2ns	V _{CC} /2	30pF	500Ω
3.3V±0.3V	3V	≤2.5ns	1.5V	50pF	500Ω
5V±0.5V	V _{CC}	≤2.5ns	V _{CC} /2	50pF	500Ω



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Figure 2. Load Circuit and Voltage Waveforms

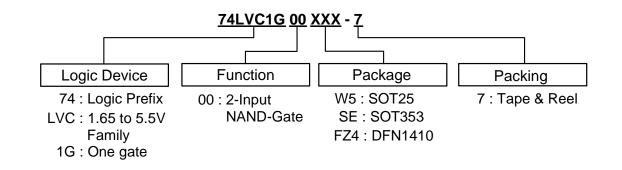
Notes:

- A. Includes test lead and test apparatus capacitance. B. All pulses are supplied at pulse repetition rate \leq 10 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as $t_{PD.}$



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Ordering Information



	Device	Package	Packaging	7" Tape a	nd Reel
	Device	Code	(Note 6)	Quantity	Part Number Suffix
Pb,	74LVC1G00W5-7	W5	SOT25	3000/Tape & Reel	-7
Pb,	74LVC1G00SE-7	SE	SOT353	3000/Tape & Reel	-7
Pb,	74LVC1G00FZ4-7	FZ4	DFN1410	5000/Tape & Reel	-7

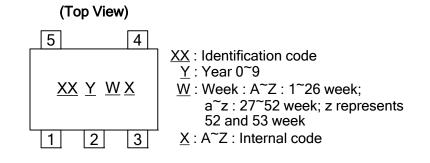
Notes: 6. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.



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Marking Information

(1) SOT25 and SOT353



Part Number	Package	Identification Code
74LVC1G00W5	SOT25	US
74LVC1G00SE	SOT353	US

(2) DFN1410

(Top View)

		XX : Identification Code
	<u>XX</u>	<u>Y</u> : Year : 0~9
	YWX	<u>W</u> : Week : A~Z : 1~26 week;
	•	a~z : 27~52 week; z represents
52 and 53 week		
		X : A~Z : Internal code

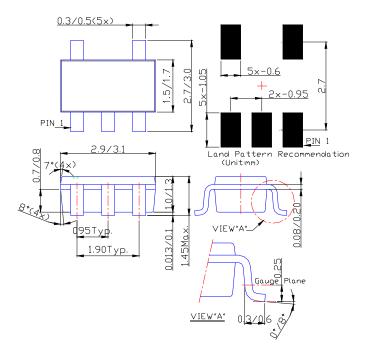
Part Number	Package	Identification Code
74LVC1G00FZ4	DFN1410	US



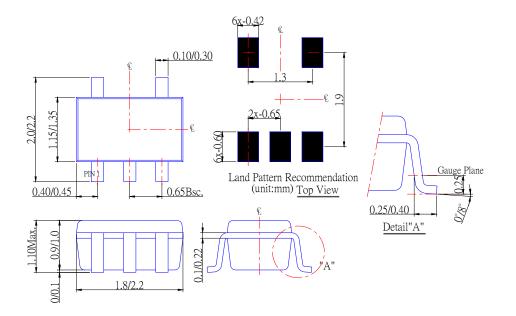
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Package Outline Dimensions (All Dimensions in mm)

(1) Package Type: SOT25



(2) Package Type: SOT353



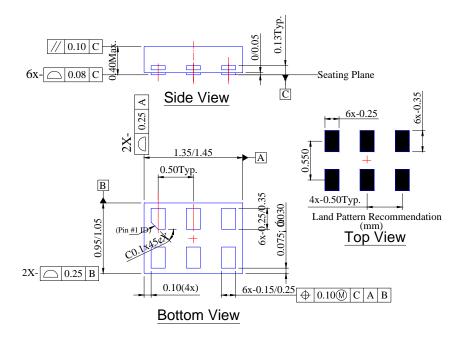
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Package Outline Dimensions (Continued)

(3) Package Type: DFN1410

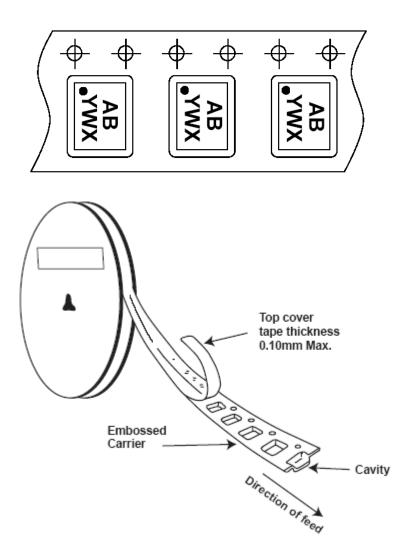


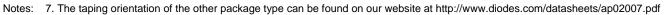


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Taping Orientation (Note 7)

For DFN1410









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